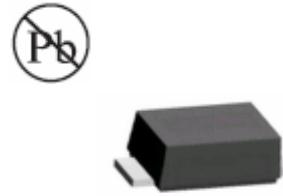


**Major Ratings and Characteristics**

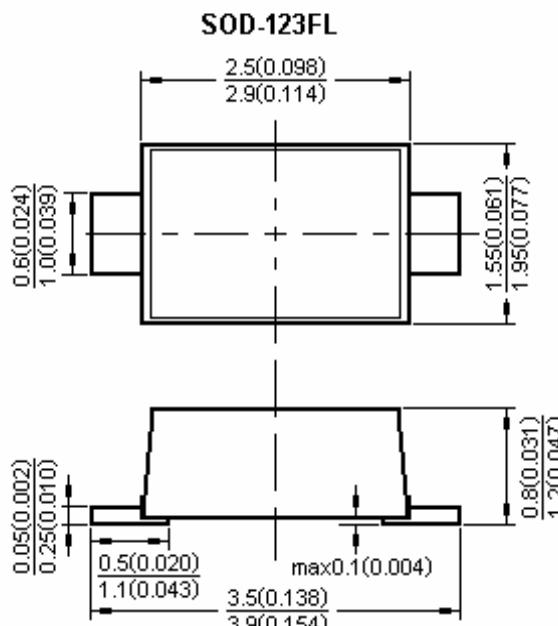
$I_{F(AV)}$	1.0 A
$V_{RRM}$	50 V to 1000 V
$I_{FSM}$	25 A
$I_R$	5 $\mu$ A
$V_F$	1.3V
$T_j \text{ max.}$	150 °C

**Features**

- Low profile space
- Ideal for automated placement
- Glass passivated chip junctions
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High temperature soldering:  
260 °C/10 seconds at terminals
- Component in accordance to  
RoHS 2002/95/1 and WEEE 2002/96/EC

**Mechanical Data**

- **Case:** JEDEC SOD-123FL molded plastic body over glass passivated chip
- **Terminals:** Solder plated, solderable per J-STD-002B and JESD22-B102D
- **Polarity:** Laser band denotes cathode end

**Maximum Ratings & Thermal Characteristics & Electrical Characteristics**

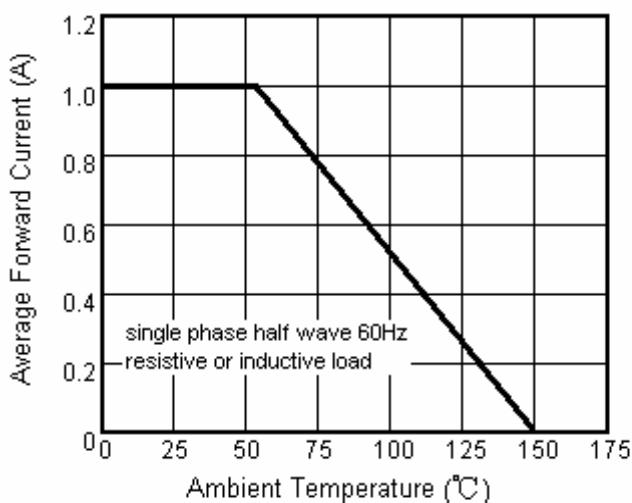
(TA = 25 °C unless otherwise noted)

	Symbol	F1A	F1B	F1D	F1G	F1J	F1K	F1M	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	$I_{F(AV)}$				1				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$				25				A
Maximum instantaneous forward voltage at 1.0A	$V_F$				1.3				V
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at Rated DC blocking voltage $T_A = 100^\circ\text{C}$	$I_R$				5.0				$\mu\text{A}$
Maximum reverse recovery time at $I_F = 0.5 \text{ A}$ , $I_R = 1.0 \text{ A}$ , $I_{rr} = 0.25 \text{ A}$	$t_{rr}$			150		250	500		nS
Typical junction capacitance at 4.0 V, 1MHz	$C_J$			15					p F
Operating junction and storage temperature range	$T_J, T_{STG}$			−55 to +150					°C

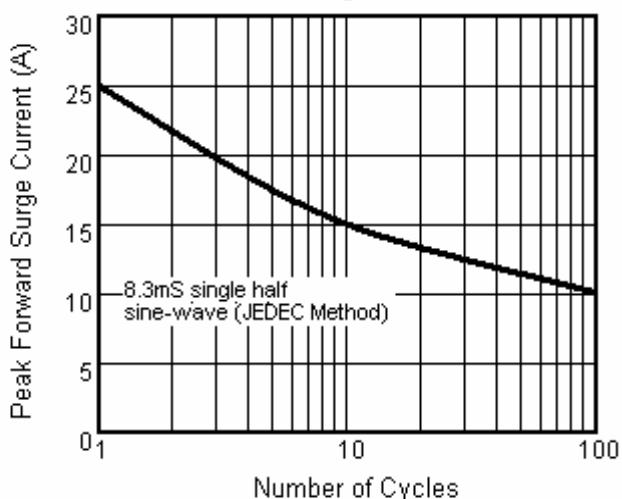
## Surface Mount Fast Recovery Rectifiers

**Characteristic Curves** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

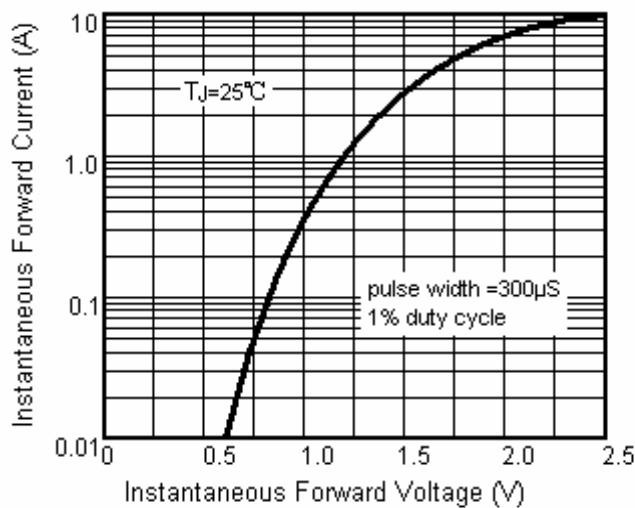
**Fig.1 Forward Current Derating Curve**



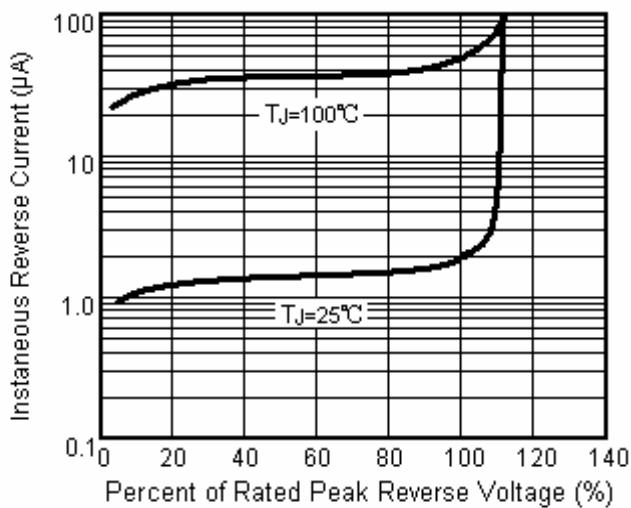
**Fig.2 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.3 Typical Instantaneous Forward Characteristics**



**Fig.4 Typical Reverse Characteristics**



**Fig.5 Typical Junction Capacitance**

